

## TL594 Pulse-Width-Modulation Control Circuit

Check for Samples: [TL594](#)

### FEATURES

- Complete PWM Power-Control Circuitry
- Uncommitted Outputs for 200-mA Sink or Source Current
- Output Control Selects Single-Ended or Push-Pull Operation
- Internal Circuitry Prohibits Double Pulse at Either Output
- Variable Dead Time Provides Control Over Total Range
- Internal Regulator Provides a Stable 5-V Reference Supply Trimmed to 1%
- Circuit Architecture Allows Easy Synchronization
- Undervoltage Lockout for Low- $V_{CC}$  Conditions

### DESCRIPTION

The TL594 device incorporates all the functions required in the construction of a pulse-width-modulation (PWM) control circuit on a single chip. Designed primarily for power-supply control, this device offers the systems engineer the flexibility to tailor the power-supply control circuitry to a specific application.

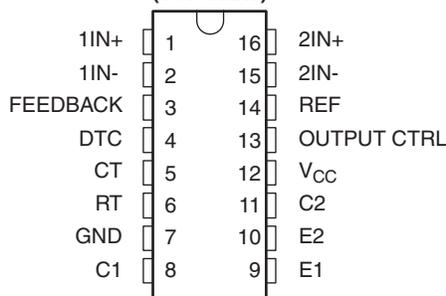
The TL594 device contains two error amplifiers, an on-chip adjustable oscillator, a dead-time control (DTC) comparator, a pulse-steering control flip-flop, a 5-V regulator with a precision of 1%, an undervoltage lockout control circuit, and output control circuitry.

The error amplifiers have a common-mode voltage range of  $-0.3\text{ V}$  to  $V_{CC} - 2\text{ V}$ . The DTC comparator has a fixed offset that provides approximately 5% dead time. The on-chip oscillator can be bypassed by terminating RT to the reference output and providing a sawtooth input to CT, or it can be used to drive the common circuitry in synchronous multiple-rail power supplies.

The uncommitted output transistors provide either common-emitter or emitter-follower output capability. Each device provides for push-pull or single-ended output operation, with selection by means of the output-control function. The architecture of these devices prohibits the possibility of either output being pulsed twice during push-pull operation. The undervoltage lockout control circuit locks the outputs off until the internal circuitry is operational.

The TL594C device is characterized for operation from  $0^{\circ}\text{C}$  to  $70^{\circ}\text{C}$ . The TL594I device is characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

D, N, NS, OR PW PACKAGE  
(TOP VIEW)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

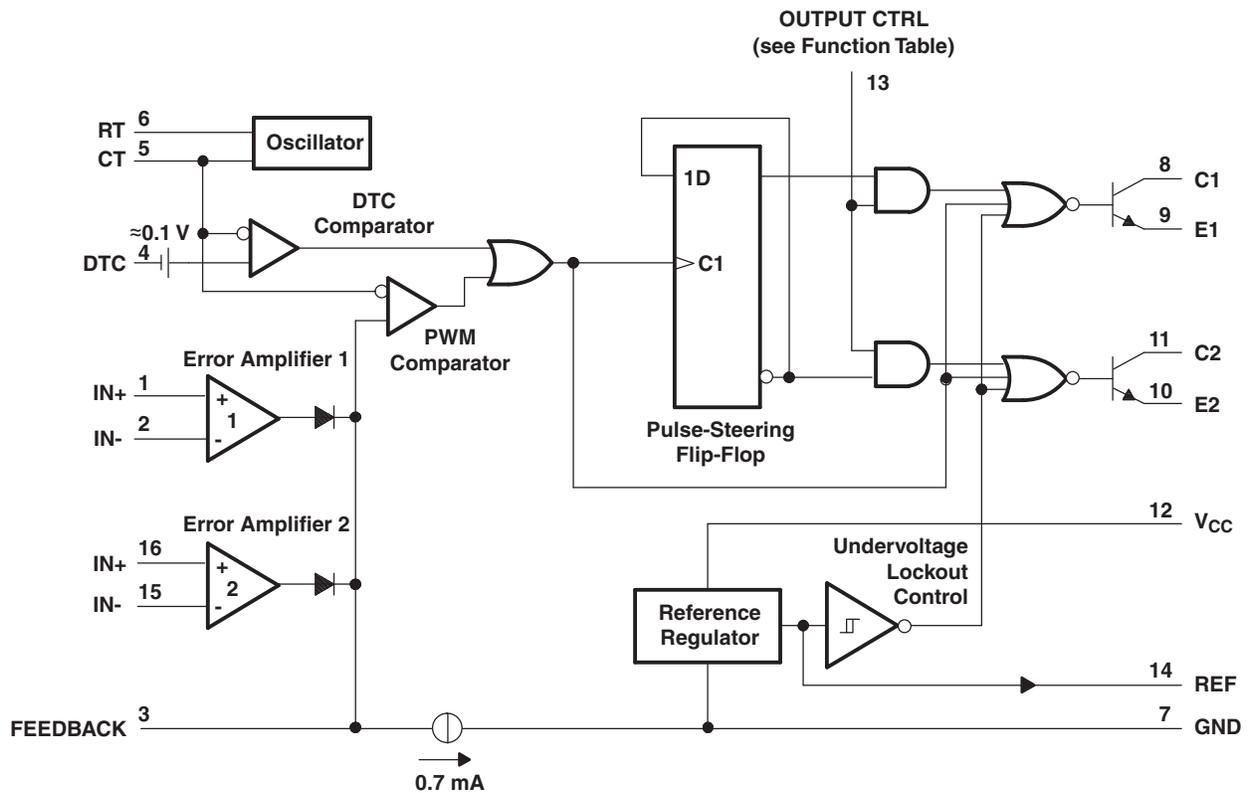


This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

**Function Table**

INPUT	OUTPUT FUNCTION
OUTPUT CTRL	
$V_I = 0$	Single-ended or parallel output
$V_I = V_{ref}$	Normal push-pull operation

**Functional Block Diagram**


## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

		VALUE	UNIT
V <sub>CC</sub>	Supply voltage <sup>(2)</sup>	41	V
	Amplifier input voltage	V <sub>CC</sub> + 0.3	V
	Collector output voltage	41	V
	Collector output current	250	mA
θ <sub>JA</sub>	Package thermal impedance <sup>(3)(4)</sup>	D package	73
		N package	67
		NS package	64
		PW package	108
T <sub>J</sub>	Operating virtual junction temperature	150	°C
T <sub>stg</sub>	Storage temperature range	–65 to 150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the network ground terminal.
- (3) Maximum power dissipation is a function of T<sub>J(max)</sub>, θ<sub>JA</sub>, and T<sub>A</sub>. The maximum allowable power dissipation at any allowable ambient temperature is P<sub>D</sub> = (T<sub>J(max)</sub> – T<sub>A</sub>)/θ<sub>JA</sub>. Operating at the absolute maximum T<sub>J</sub> of 150°C can affect reliability.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.

## Recommended Operating Conditions

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	7	40	V
V <sub>I</sub>	Amplifier input voltage	–0.3	V <sub>CC</sub> – 2	V
V <sub>O</sub>	Collector output voltage		40	V
	Collector output current (each transistor)		200	mA
	Current into FEEDBACK terminal		0.3	mA
C <sub>T</sub>	Timing capacitor	0.47	10000	nF
R <sub>T</sub>	Timing resistor	1.8	500	kΩ
f <sub>osc</sub>	Oscillator frequency	1	300	kHz
T <sub>A</sub>	Operating free-air temperature	TL594C	0	70
		TL594I	–40	85

## Electrical Characteristics

 $V_{CC} = 15\text{ V}$ , over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS <sup>(1)</sup>	MIN	TYP <sup>(2)</sup>	MAX	UNIT
<b>Reference Section</b>					
Output voltage (REF)	$I_O = 1\text{ mA}$ , $T_A = 25^\circ\text{C}$	4.95	5	5.05	V
Input regulation	$V_{CC} = 7\text{ V to }40\text{ V}$ , $T_A = 25^\circ\text{C}$		2	25	mV
Output regulation	$I_O = 1\text{ mA to }10\text{ mA}$ , $T_A = 25^\circ\text{C}$		14	35	mV
Output-voltage change with temperature	$\Delta T_A = \text{MIN to MAX}$		2	10	mV/V
Short-circuit output current <sup>(3)</sup>	$V_{ref} = 0$	10	35	50	mA
<b>Amplifier Section (see Figure 1)</b>					
Input offset voltage, error amplifier	FEEDBACK = 2.5 V		2	10	mV
Input offset current	FEEDBACK = 2.5 V		25	250	nA
Input bias current	FEEDBACK = 2.5 V		0.2	1	$\mu\text{A}$
Common-mode input voltage range, error amplifier	$V_{CC} = 7\text{ V to }40\text{ V}$	0.3 to $V_{CC} - 2$			V
Open-loop voltage amplification, error amplifier	$\Delta V_O = 3\text{ V}$ , $R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }3.5\text{ V}$	70	95		dB
Unity-gain bandwidth	$V_O = 0.5\text{ V to }3.5\text{ V}$ , $R_L = 2\text{ k}\Omega$		800		kHz
Common-mode rejection ratio, error amplifier	$V_{CC} = 40\text{ V}$ , $T_A = 25^\circ\text{C}$	65	80		dB
Output sink current, FEEDBACK	$V_{ID} = -15\text{ mV to }-5\text{ V}$ , FEEDBACK = 0.5 V	0.3	0.7		mA
Output source current, FEEDBACK	$V_{ID} = 15\text{ mV to }5\text{ V}$ , FEEDBACK = 3.5 V	-2			mA
<b>Oscillator Section, <math>C_T = 0.01\text{ }\mu\text{F}</math>, <math>R_T = 12\text{ k}\Omega</math> (see Figure 2)</b>					
Frequency			10		kHz
Standard deviation of frequency <sup>(4)</sup>	All values of $V_{CC}$ , $C_T$ , $R_T$ , and $T_A$ constant		100		Hz/kHz
Frequency change with voltage	$V_{CC} = 7\text{ V to }40\text{ V}$ , $T_A = 25^\circ\text{C}$		1		Hz/kHz
Frequency change with temperature <sup>(5)</sup>	$\Delta T_A = \text{MIN to MAX}$			50	Hz/kHz
<b>Dead-Time Control Section (see Figure 2)</b>					
Input bias current	$V_I = 0\text{ to }5.25\text{ V}$		-2	-10	$\mu\text{A}$
Maximum duty cycle, each output	DTC = 0 V	0.45			
Input threshold voltage	Zero duty cycle		3	3.3	V
	Maximum duty cycle	0			
<b>Output Section</b>					
Collector off-state current	$V_C = 40\text{ V}$ , $V_E = 0\text{ V}$ , $V_{CC} = 40\text{ V}$		2	100	$\mu\text{A}$
	DTC and OUTPUT CTRL = 0 V, $V_C = 15\text{ V}$ , $V_E = 0\text{ V}$ , $V_{CC} = 1\text{ V to }3\text{ V}$		4	200	
Emitter off-state current	$V_{CC} = V_C = 40\text{ V}$ , $V_E = 0$			-100	$\mu\text{A}$
Collector-emitter saturation voltage	Common emitter, $V_E = 0$ , $I_C = 200\text{ mA}$		1.1	1.3	V
	Emitter follower, $V_C = 15\text{ V}$ , $I_E = -200\text{ mA}$		1.5	2.5	
Output control input current	$V_I = V_{ref}$			3.5	mA

(1) For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

(2) All typical values, except for parameter changes with temperature, are at  $T_A = 25^\circ\text{C}$ .

(3) Duration of the short circuit should not exceed one second.

(4) Standard deviation is a measure of the statistical distribution about the mean, as derived from the formula:

$$\sigma = \sqrt{\frac{\sum_{n=1}^N (x_n - \bar{X})^2}{N - 1}}$$

(5) Temperature coefficient of timing capacitor and timing resistor is not taken into account.

## Electrical Characteristics (continued)

$V_{CC} = 15\text{ V}$ , over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS <sup>(1)</sup>	MIN	TYP <sup>(2)</sup>	MAX	UNIT
<b>PWM Comparator Section (see Figure 2)</b>					
Input threshold voltage, FEEDBACK	Zero duty cycle		4	4.5	V
Input sink current, FEEDBACK	FEEDBACK = 0.5 V	0.3	0.7		mA
<b>Undervoltage Lockout Section (see Figure 2)</b>					
Threshold voltage	$T_A = 25^\circ\text{C}$			6	V
	$\Delta T_A = \text{MIN to MAX}$	3.5		6.9	
Hysteresis <sup>(6)</sup>		100			mV
<b>Overall Device</b>					
Standby supply current	$R_T$ at $V_{ref}$ , All other inputs and outputs open	$V_{CC} = 15\text{ V}$	9	15	mA
		$V_{CC} = 40\text{ V}$	11	18	
Average supply current	DTC = 2 V, See Figure 2		12.4		mA

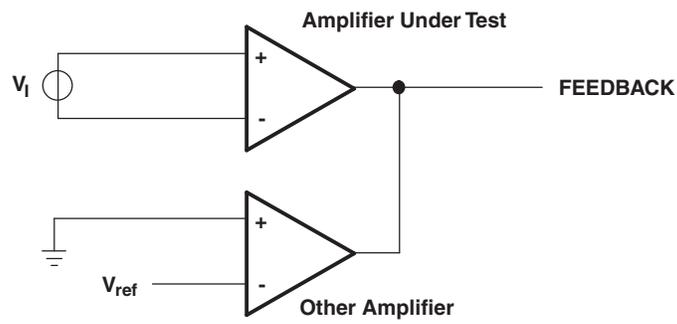
(6) Hysteresis is the difference between the positive-going input threshold voltage and the negative-going input threshold voltage.

## Switching Characteristics

$V_{CC} = 15\text{ V}$ ,  $T_A = 25^\circ\text{C}$ , over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Output-voltage rise time	Common-emitter configuration (see Figure 3)		100	200	ns
Output-voltage fall time			30	100	ns
Output-voltage rise time	Emitter-follower configuration (see Figure 4)		200	400	ns
Output-voltage fall time			45	100	ns

**Parameter Measurement Information**



**Figure 1. Amplifier-Characteristics Test Circuit**

Parameter Measurement Information (continued)

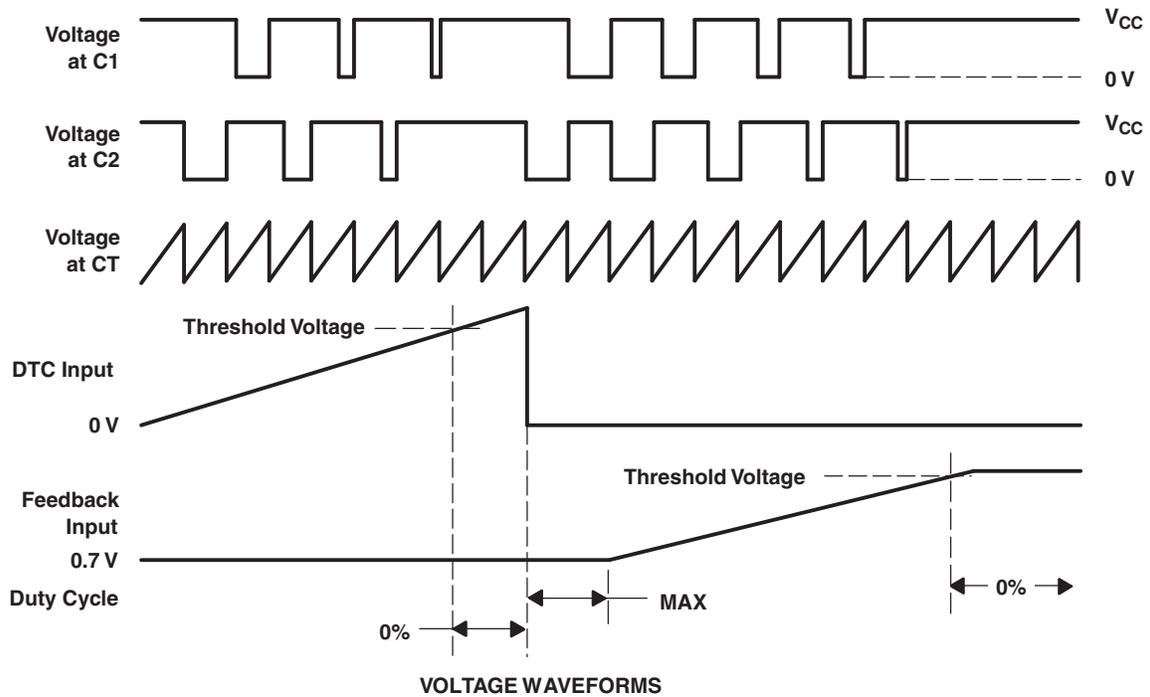
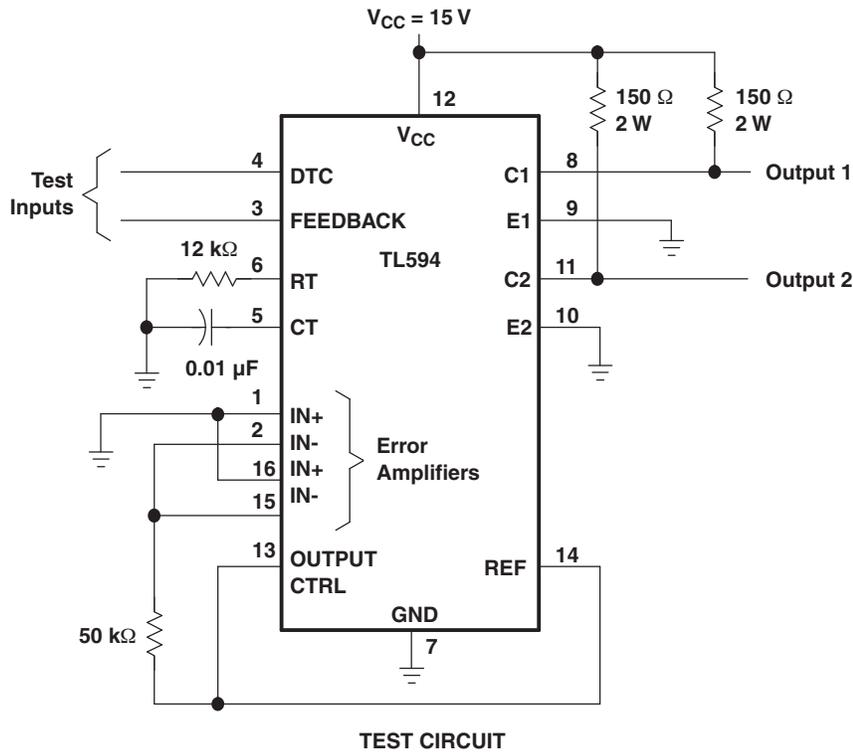
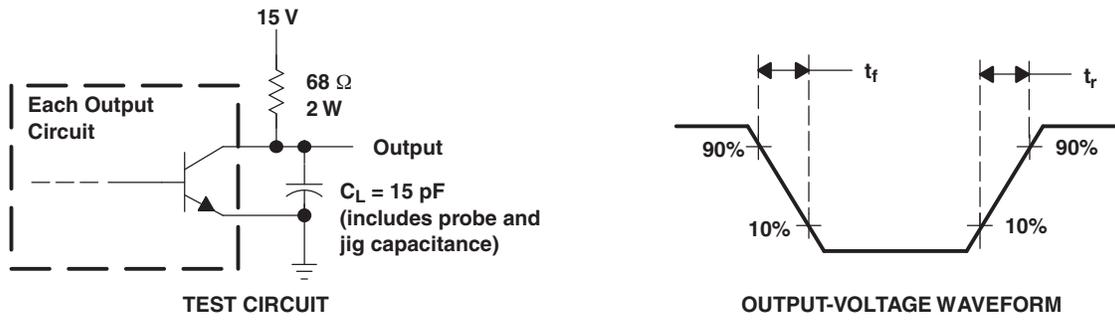
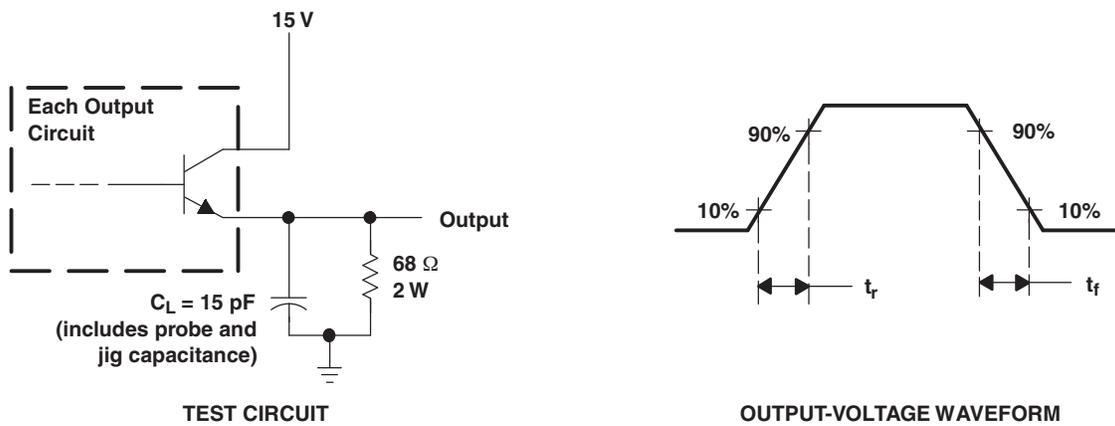


Figure 2. Operational Test Circuit and Waveforms

**Parameter Measurement Information (continued)**

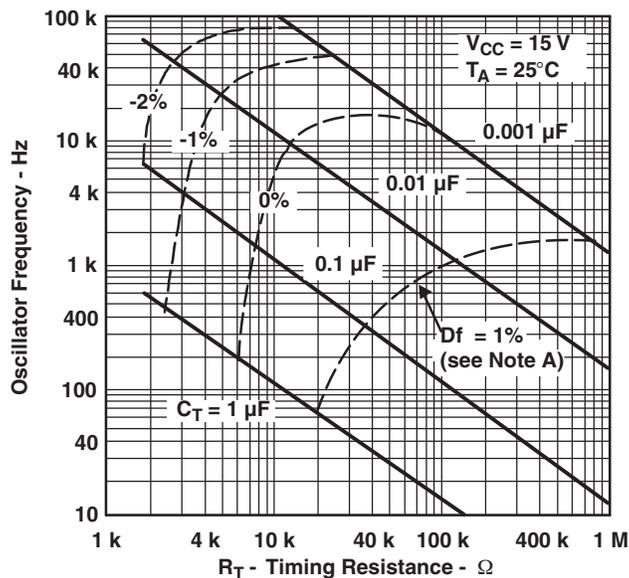


**Figure 3. Common-Emitter Configuration**



**Figure 4. Emitter-Follower Configuration**

Typical Characteristics



A. Frequency variation ( $\Delta f$ ) is the change in oscillator frequency that occurs over the full temperature range.

Figure 5. Oscillator Frequency and Frequency Variation vs Timing Resistance

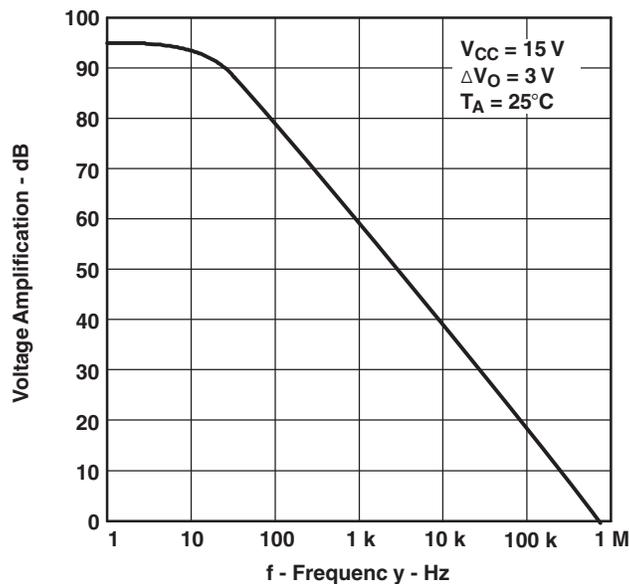
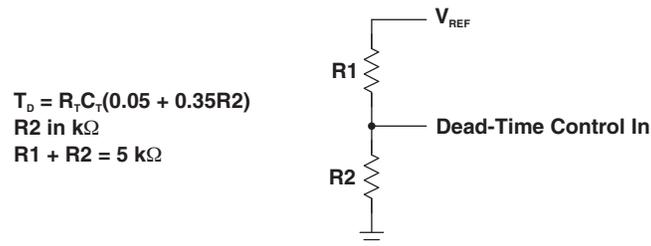


Figure 6. Amplifier Voltage Amplification vs Frequency

## APPLICATION INFORMATION

### How to Set Dead Time

The primary function of the dead-time control is to control the minimum off time of the output of the TL594 device. The dead-time control input provides control from 5% to 100% dead time. The TL594 device can be tailored to the specific power transistor switches that are used, to ensure that the output transistors never experience a common on-time. The bias circuit for the basic function is shown in [Figure 7](#).



**Figure 7. Setting Dead Time**

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**REVISION HISTORY**

<b>Changes from Revision G (January 2007) to Revision H</b>	<b>Page</b>
• Updated document to new TI data sheet format - no specification changes. ....	<b>1</b>
• Added ESD warning. ....	<b>2</b>
• Removed Ordering Information table. ....	<b>2</b>

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**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TL594CD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL594C	<a href="#">Samples</a>
TL594CDE4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL594C	<a href="#">Samples</a>
TL594CDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL594C	<a href="#">Samples</a>
TL594CDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	0 to 70	TL594C	<a href="#">Samples</a>
TL594CDRG3	PREVIEW	SOIC	D	16		TBD	Call TI	Call TI	0 to 70	TL594C	
TL594CDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL594C	<a href="#">Samples</a>
TL594CN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL594CN	<a href="#">Samples</a>
TL594CNE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TL594CN	<a href="#">Samples</a>
TL594CNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL594	<a href="#">Samples</a>
TL594CNSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TL594	<a href="#">Samples</a>
TL594CPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T594	<a href="#">Samples</a>
TL594CPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T594	<a href="#">Samples</a>
TL594CPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	T594	<a href="#">Samples</a>
TL594ID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL594I	<a href="#">Samples</a>
TL594IDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL594I	<a href="#">Samples</a>
TL594IDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL594I	<a href="#">Samples</a>
TL594IDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL594I	<a href="#">Samples</a>

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TL594IN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL594IN	<a href="#">Samples</a>
TL594INE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TL594IN	<a href="#">Samples</a>
TL594INSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL594I	<a href="#">Samples</a>
TL594INSRG4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL594I	<a href="#">Samples</a>
TL594IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	Z594	<a href="#">Samples</a>
TL594IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	Z594	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

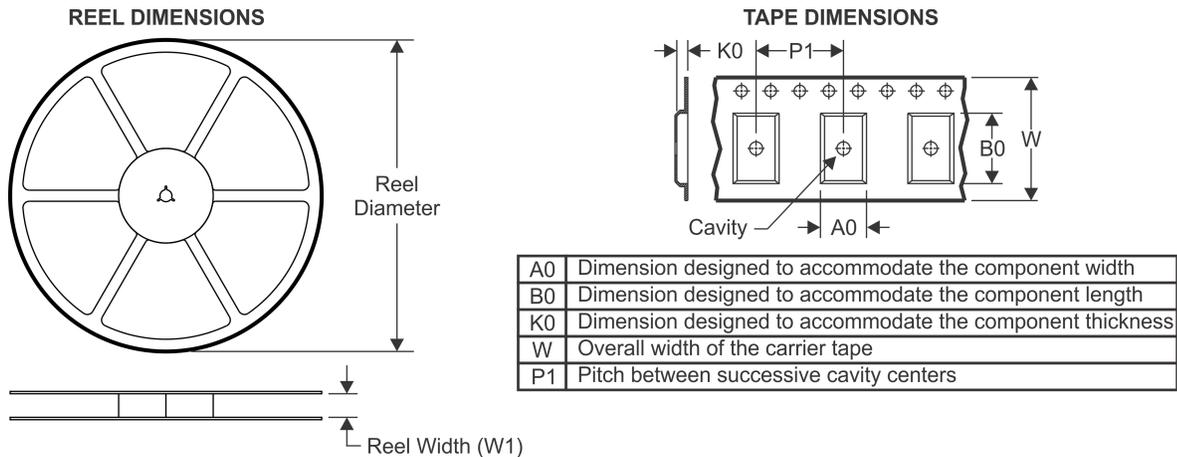
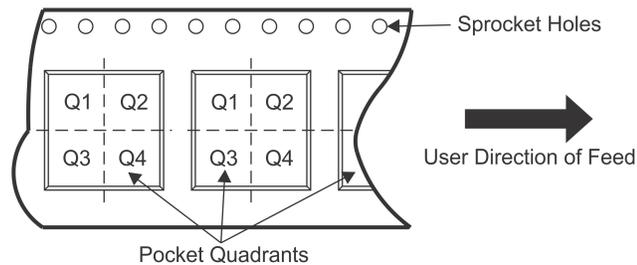
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

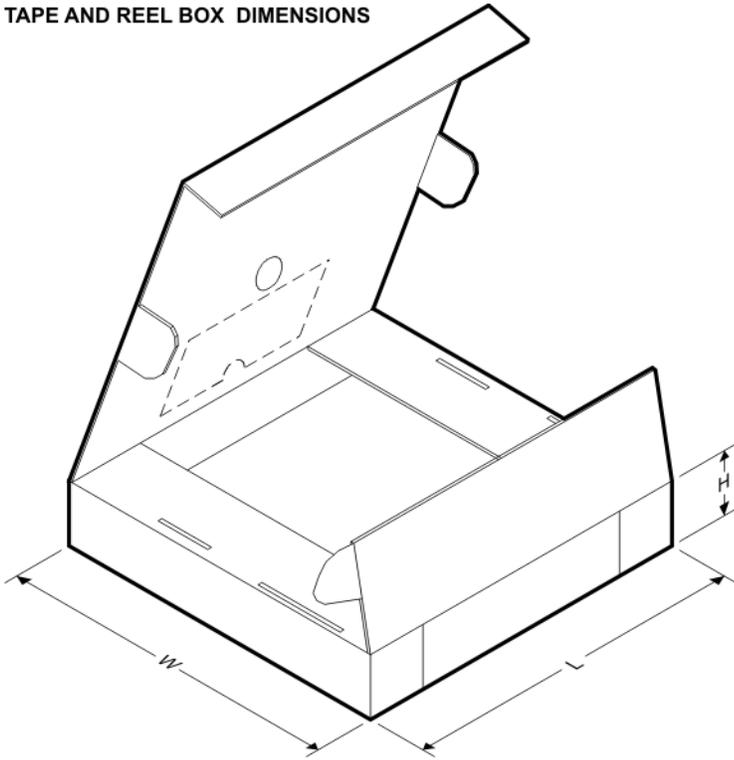
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**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL594CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TL594CDRG4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TL594CPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL594IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TL594IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


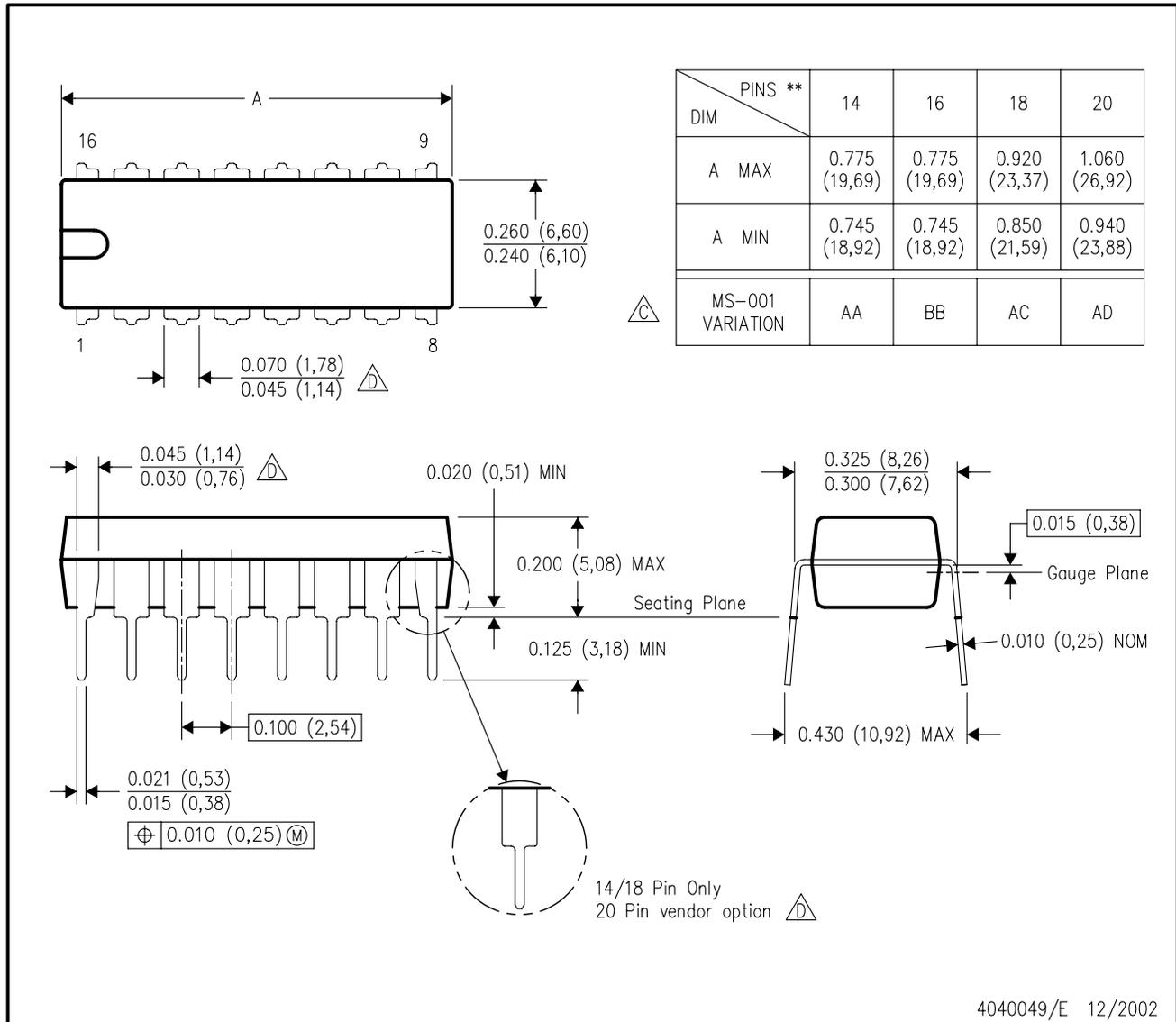
\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL594CDR	SOIC	D	16	2500	333.2	345.9	28.6
TL594CDRG4	SOIC	D	16	2500	333.2	345.9	28.6
TL594CPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
TL594IDR	SOIC	D	16	2500	333.2	345.9	28.6
TL594IPWR	TSSOP	PW	16	2000	367.0	367.0	35.0

N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

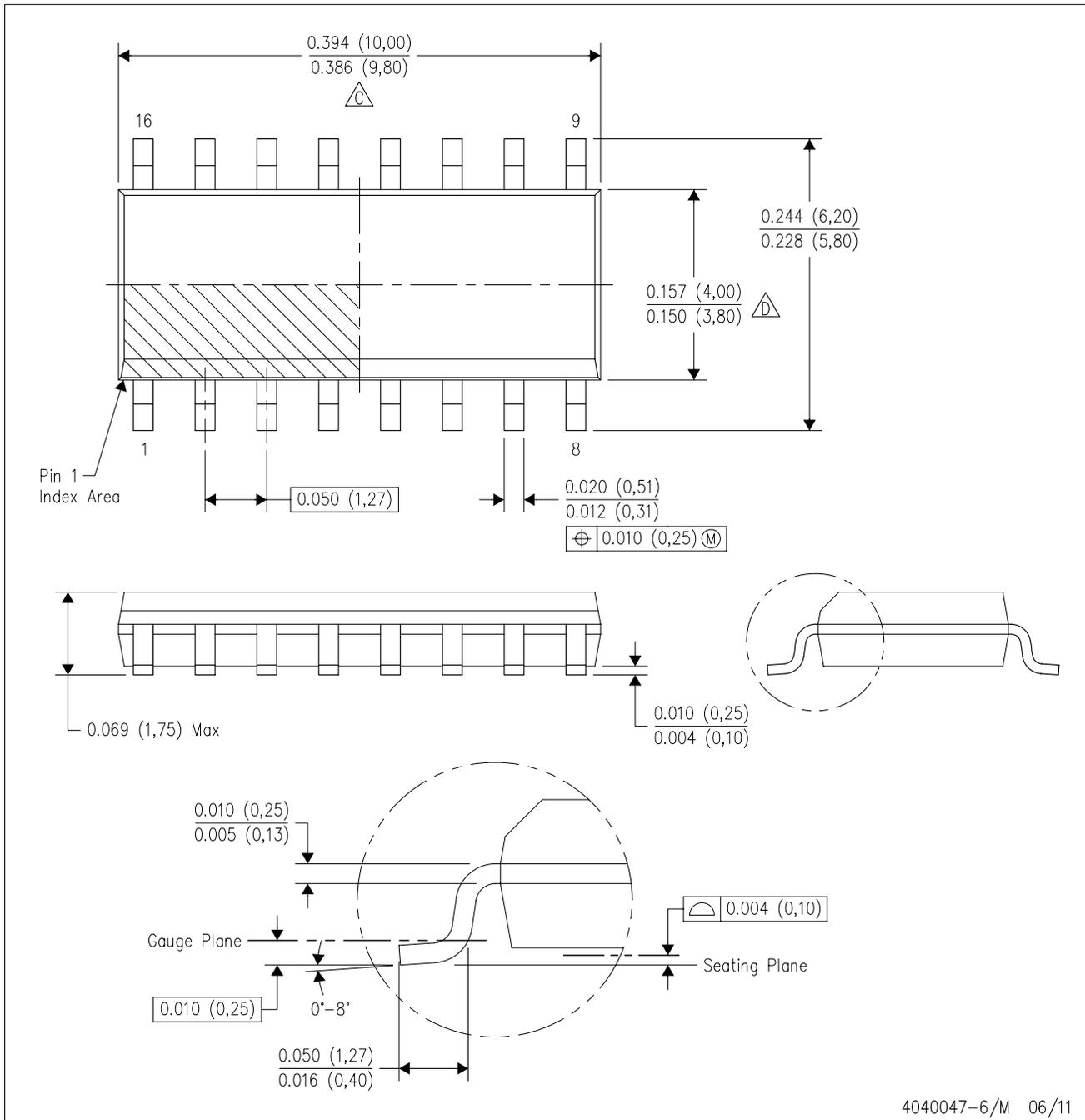
16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
  - The 20 pin end lead shoulder width is a vendor option, either half or full width.

D (R-PDSO-G16)

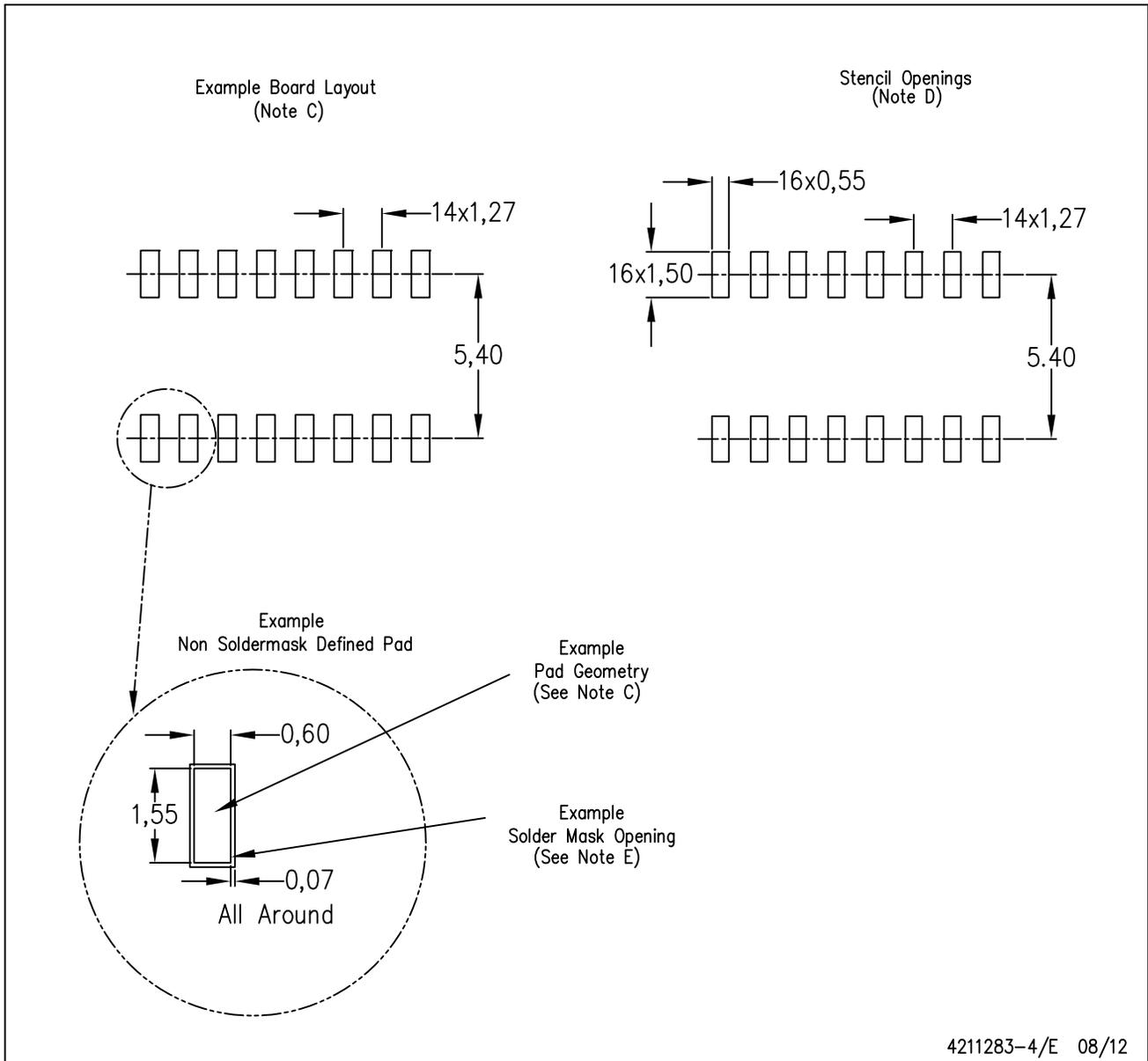
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

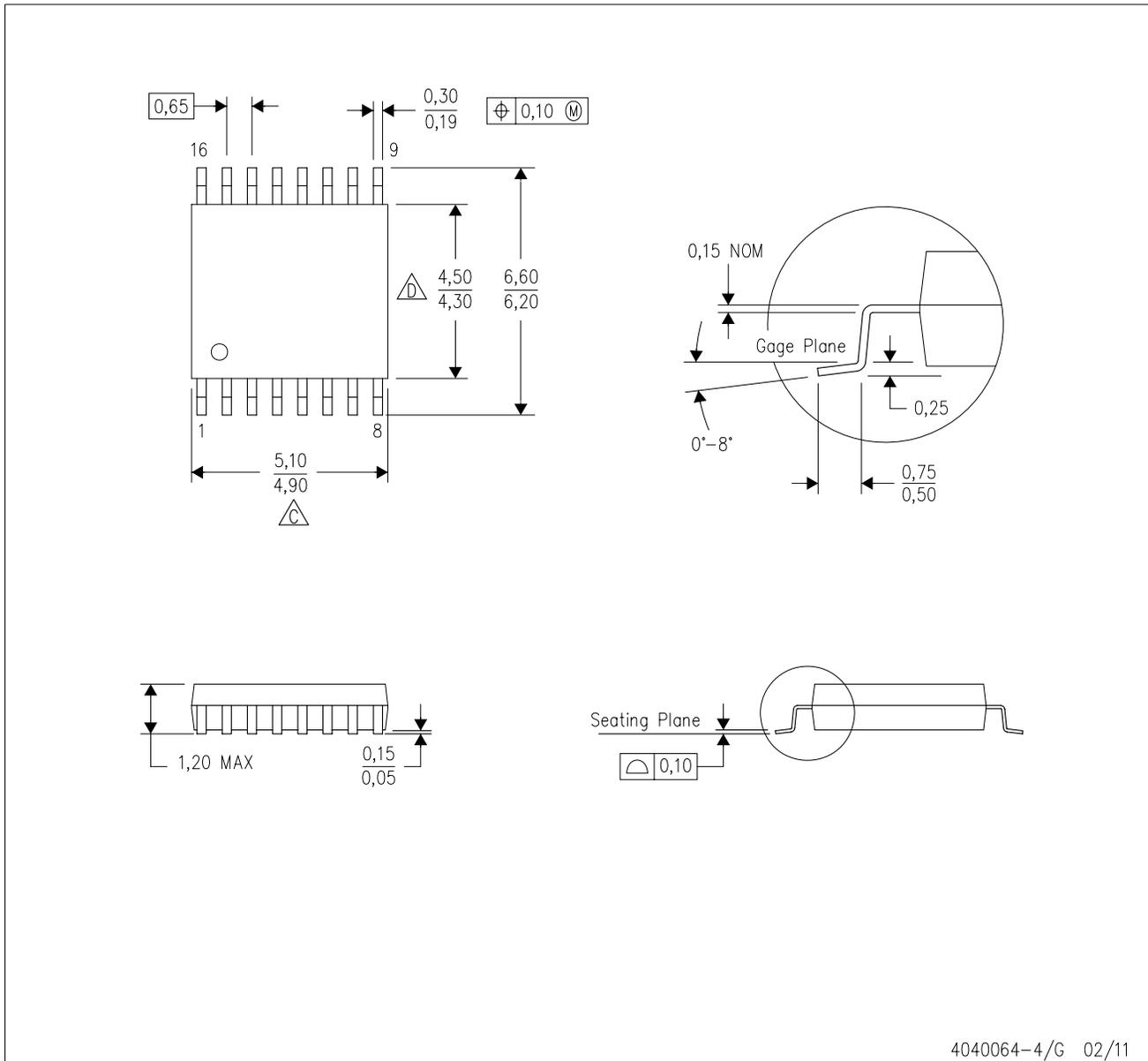
PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE

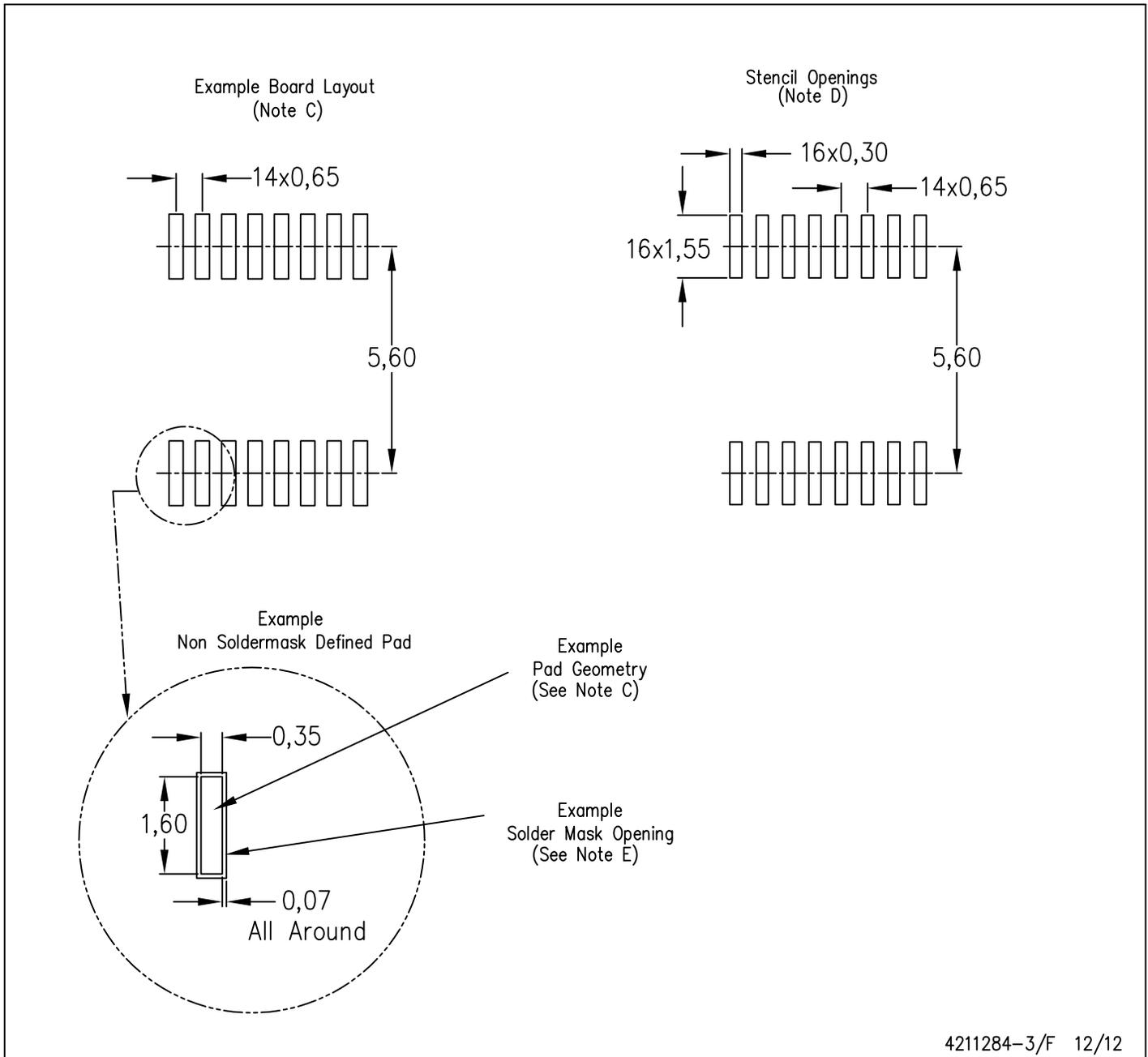


4040064-4/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  -  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
  -  D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
  - E. Falls within JEDEC MO-153

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



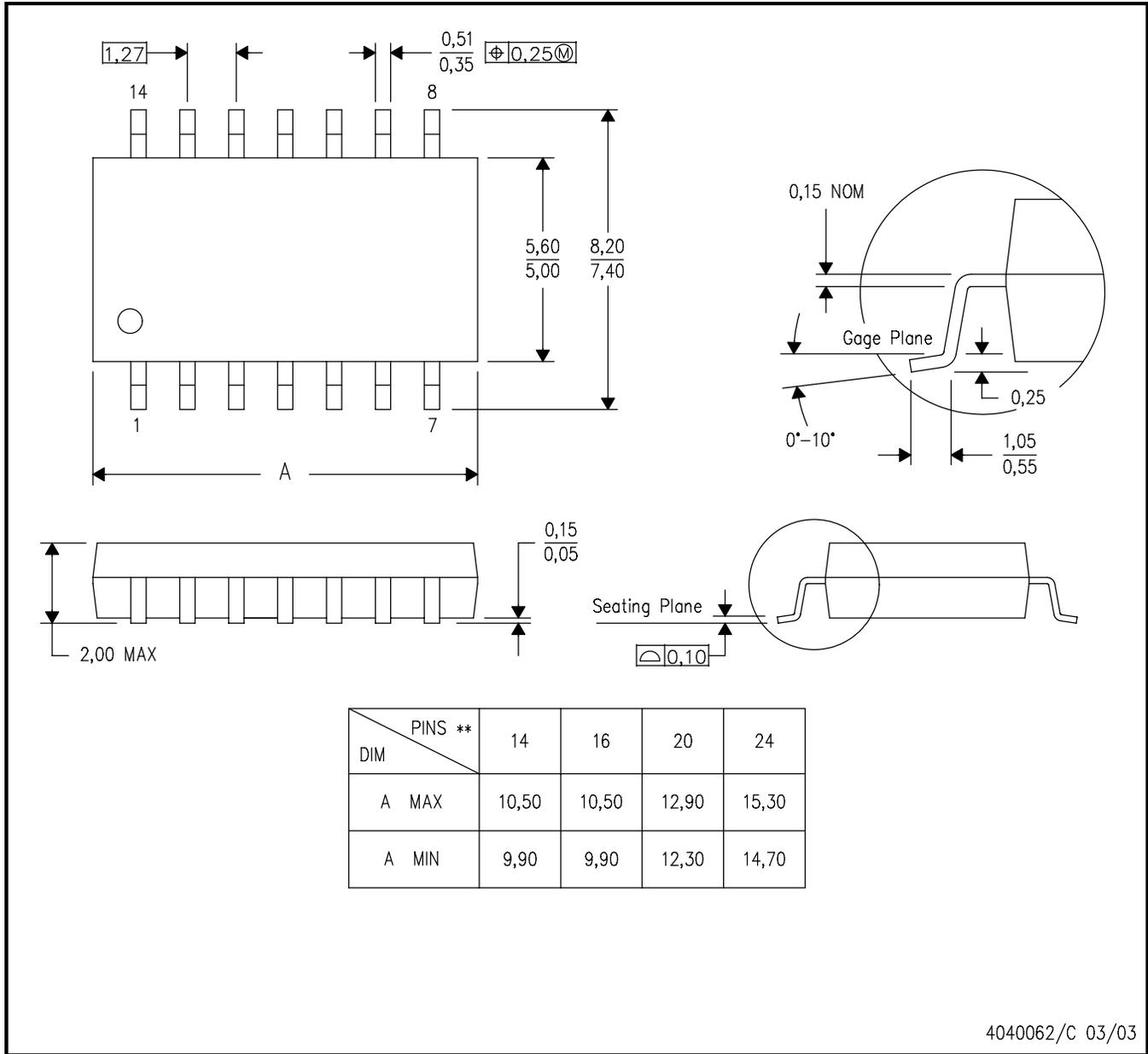
- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

# MECHANICAL DATA

NS (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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